# Nihon Inter Electronics Corporation

### FRD MODULE 30A/400V

### P2H30F4

#### **FEATURES**

\* Compatible with Isolated Base SOT227

- \* Dual Separated Diodes
- \* Ultra Fast Recovery
- \* Low Forward Voltage Drop
- \* High Surge Capability

#### TYPICAL APPLICATIONS

\* High Frequency Rectification

See the Next Page

**OUTLINE DRAWING** 

### Maximum Ratings

#### Approx Net Weight:35g

Parameter	Symbol	Type / Grade		I I
		P2H30F4	-	Unit
Repetitive Peak Reverse Voltage *1	V <sub>RRM</sub>	400	-	V
Non Repetitive Peak Reverse Voltage *1	Vrsm	-	-	V

Para	meter		Conditions	Max Rated Value	Unit
Average Rectified	rerage Rectified Output Current *1 $I_{O(AV)}$ 50Hz Half Sine Wave condition $T_{C}=75^{\circ}C$		50Hz Half Sine Wave condition Tc=75°C	30	A
RMS Forward Cur	rent *1	I <sub>F(RMS)</sub>		47	A
Surge Forward Current *1		Ifsm	50 Hz Half Sine Wave,1Pulse Non-repetitive	300	A
I Squared t *1		I2t	2msec to 10msec	450	A <sup>2</sup> s
Operating JunctionTemperature Range		Tjw		-40 to +150	$^{\circ}\mathrm{C}$
Storage Temperature Range		Tstg		-40 to +125	$^{\circ}\mathrm{C}$
Isoration Voltage		Viso	Base Plate to Terminals, AC1min	2500	V
Mounting torque	Case mounting	Ftor	M4Screw	1.5(1.4)	N•m
	Terminals		M4Screw	1.5(1.4)	1 N•111

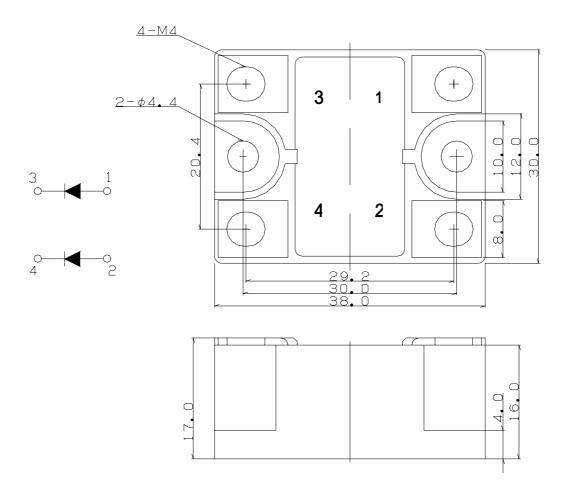
#### Electrical • Thermal Characteristics

Characteristics	Symbol	Test Conditions		Unit
Peak Reverse Current *1	$I_{RM}$	V <sub>RM</sub> = V <sub>RRM</sub> , Tj= 25°C	50	μА
Peak Forward Voltage *1	$V_{\mathrm{FM}}$	$I_{FM}=30A$ , $Tj=25$ °C	1.33	V
Reverse Recovery Time	trr	Tj=25°C , I <sub>FM</sub> =10A, -di/dt=50A/μs	60	ns
Thermal Resistance *1	Rth(j-c)	Junction to Case	1.53	
		Base Plate to Heat Sink with Thermal Compound	0.3	°C/W

<sup>\*1:</sup> Value Per 1Arm

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### P2H30F4 OUTLINE DRAWING (Dimensions in mm)



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